# 2SC4853A

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## RF Transistor 6V, 15mA, fT=5GHz, NPN Single MCP

### **Features**

• Low-voltage, low-current operation : fT=5GHz typ (VCE=1V, IC=1mA) : |S21e|<sup>2</sup>=7dB typ (f=1GHz) : NF=2.6dB typ (f=1GHz)

### **Specifications**

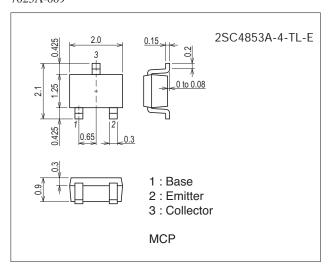
### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		12	V
Collector-to-Emitter Voltage	VCEO		6	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		1.5	V
Collector Current	IC		15	mA
Collector Dissipation	PC		90	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

### **Package Dimensions**

unit : mm (typ) 7023A-009

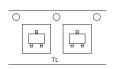


### Product & Package Information

• Package : MCP

• JEITA, JEDEC : SC-70, SOT-323 • Minimum Packing Quantity : 3,000 pcs./reel

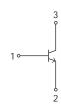
### Packing Type: TL





Marking

### **Electrical Connection**



### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
Parameter	Syllibol	Conditions	min	typ	max	Ullit
Collector Cutoff Current	ICBO	V <sub>CB</sub> =5V, I <sub>E</sub> =0A			1.0	μΑ
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =1V, I <sub>C</sub> =0A			10	μΑ
DC Current Gain	hFE	V <sub>CE</sub> =1V, I <sub>C</sub> =1mA	60*		270*	
Gain-Bandwidth Product	fT	V <sub>CE</sub> =1V, I <sub>C</sub> =1mA		5		GHz
Output Capacitance	Cob	V <sub>CB</sub> =1V, f=1MHz		0.6	1.0	pF
Forward Transfer Gain	S21e  <sup>2</sup> 1	V <sub>CE</sub> =1V, I <sub>C</sub> =1mA, f=1GHz	4.5	7		dB
Forward Iransier Gairi	S21e  <sup>2</sup> 2	V <sub>CE</sub> =2V, I <sub>C</sub> =3mA, f=1GHz		10.5		dB
Noise Figure	NF1	V <sub>CE</sub> =1V, I <sub>C</sub> =1mA, f=1GHz		2.6	4.5	dB
Noise i iguie	NF2	V <sub>CE</sub> =2V, I <sub>C</sub> =3mA, f=1GHz		1.9		dB

### $^*$ : The 2SC4853A is classified by 1mA hFE as follows:

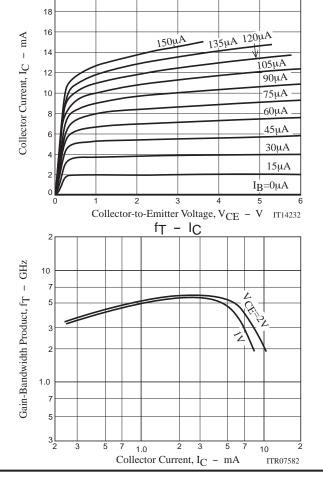
Rank	3	4	5	
hFE	60 to 120	90 to 180	135 to 270	

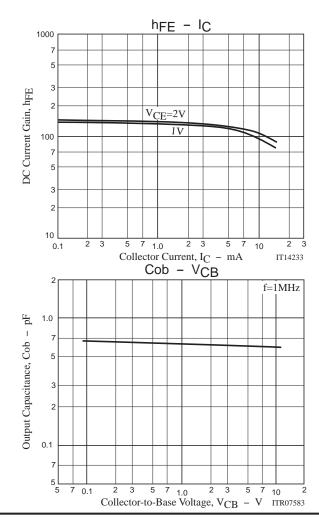
IC - VCE

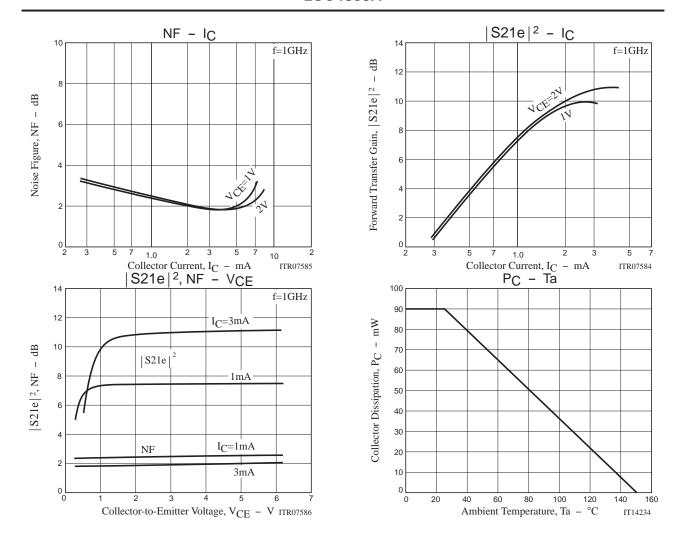
### **Ordering Information**

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Device	Package	Shipping	memo	
2SC4853A-4-TL-E	MCP	3,000pcs./reel	Pb Free	

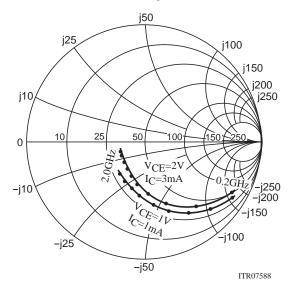




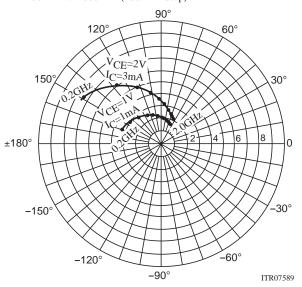


### **S** Parameters

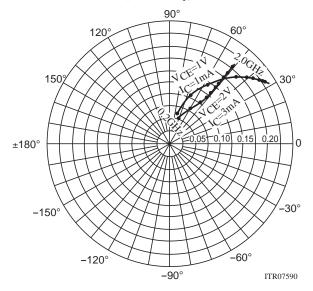
S11e f=200MHz to 2000MHz(200MHz Step)



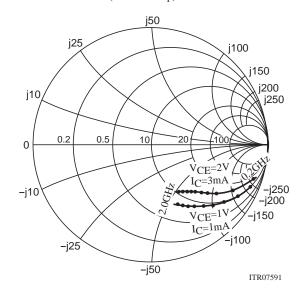
S21e f=200MHz to 2000MHz(200MHz Step)



S12e f=200MHz to 2000MHz(200MHz Step)



S22e f=200MHz to 2000MHz(200MHz Step)



### 2SC4853A

### S Parameters (Common emitter)

 $V_{CE}=1V$ ,  $I_{C}=1mA$ ,  $Z_{O}=50\Omega$ 

Freq(MHz)	S11	∠S11	S21	∠S21	S12	∠S12	S22	∠S22
200	0.940	-17.9	3.228	159.6	0.058	77.1	0.972	-12.2
400	0.863	-33.7	2.983	143.7	0.107	66.6	0.914	-22.7
600	0.778	-48.0	2.732	129.9	0.145	58.1	0.844	-31.7
800	0.698	-60.5	2.469	117.7	0.173	50.9	0.773	-39.6
1000	0.608	-73.5	2.320	106.2	0.195	45.4	0.717	-46.0
1200	0.546	-84.7	2.106	96.3	0.210	40.9	0.668	-51.7
1400	0.470	-96.2	1.977	87.1	0.129	37.6	0.624	-56.5
1600	0.418	-106.4	1.826	78.8	0.224	35.3	0.590	-60.6
1800	0.388	-117.3	1.700	72.2	0.230	33.8	0.562	-64.3
2000	0.354	-127.0	1.615	65.9	0.234	32.9	0.546	-67.5

### $V_{\text{CE}}\!\!=\!\!2V\!,\,I_{\text{C}}\!\!=\!\!3\text{mA},\,Z_{\text{O}}\!\!=\!\!50\Omega$

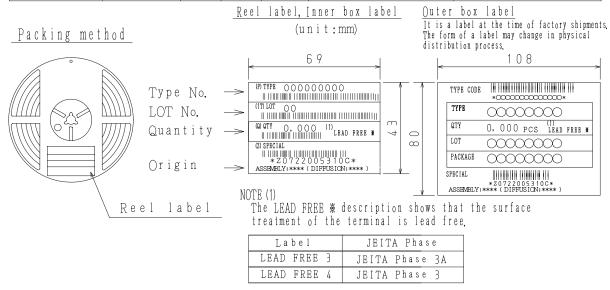
Freq(MHz)	S11	∠S11	S21	∠S21	S12	∠S12	S22	∠S22
200	0.839	-30.6	7.428	149.3	0.050	71.4	0.916	-18.3
400	0.672	-53.7	6.016	128.5	0.083	60.6	0.778	-30.2
600	0.536	-71.7	4.908	113.6	0.105	55.1	0.672	-37.1
800	0.431	-85.7	4.073	101.9	0.121	52.5	0.597	-41.9
1000	0.360	-99.0	3.494	92.7	0.135	51.4	0.548	-45.7
1200	0.310	-111.4	3.033	84.4	0.150	50.9	0.514	-49.2
1400	0.265	-122.6	2.694	77.4	0.162	50.9	0.492	-52.3
1600	0.242	-134.7	2.422	70.9	0.175	51.0	0.475	-55.6
1800	0.228	-148.0	2.205	65.9	0.189	51.1	0.461	-59.0
2000	0.217	-157.2	2.061	60.8	0.205	51.0	0.456	-61.8

### **Embossed Taping Specification**

### 2SC4853A-4-TL-E

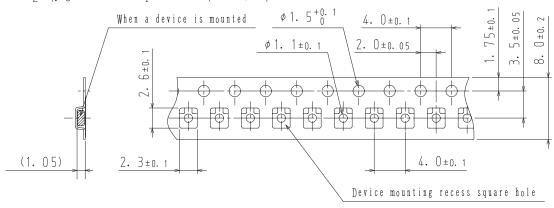
### 1. Packing Format

Package Na	me Carrier Tape	Maximum Number of devices contained (pcs)			Packing	format
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
MCP	MCP	3, 000	15, 000	90,000	5 reels contained	6 inner boxes contained
					Dimensions:mm (external)	Dimensions:mm (external)
					183×72×185	440×195×210

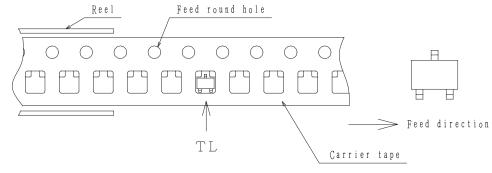


### 2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction



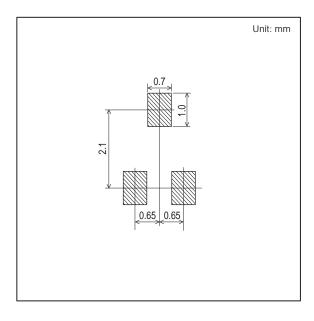
Those with oen electrode terminal on the feed hole side·····TL

### **Outline Drawing**

2SC4853A-4-TL-E

# Mass (g) Unit 0.006 . For reference mm

### Land Pattern Example



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